



16-BIT, HIGH-SPEED, LOW-NOISE, VOLTAGE OUTPUT DIGITAL-TO-ANALOG CONVERTER

Check for Samples: DAC8581

FEATURES

- 16-Bit Monotonic
- ±5-V Rail-to-Rail Output
- Very Low Glitch: 0.5 nV-s
- Fast Settling: 0.65 μs
- Fast Slew Rate: 35 V/µs
- Low Noise: 20 nV/√Hz
- ±25-mA Load Drive
- ±5-V Dual Power Supply
- Single External Reference
- Power-On Reset to Midscale
- 3-MSPS Update Rate
- SPI™ Interface, Up to 50 MHz
- 1.8-V-5-V Logic Compatible
- Twos Complement Data Format
- Hardware Reset to Midscale
- TSSOP-16 Package

APPLICATIONS

- Industrial Process Control
- CRT Projection TV Digital Convergence
- Waveform Generation
- Automated Test Equipment
- Ultrasound

DESCRIPTION

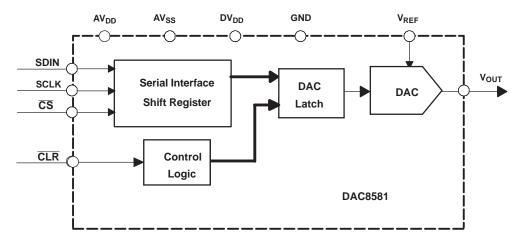
The DAC8581 is a 16-bit, high-speed, low-noise DAC operating from dual ±5-V power supplies. The DAC8581 is monotonic, and has exceptionally low noise and exceptionally low glitch. The DAC8581 high-performance, rail-to-rail output buffer is capable of settling within 0.65 µs for a 10-V step. Small-signal settling time is well under 0.3 µs, supporting data update rates up to 3 MSPS. A power-on-reset circuit sets the output at midscale voltage on power up.

The DAC8581 is simple to use, with a single external reference and a standard 3-wire SPI interface that allows clock rates up to 50 MHz.

Also see the DAC8580, a member of the same family. The DAC8580 combines DAC8581 performance with an on-chip, 16x over-sampling digital filter.

The DAC8581 is specified over the -40°C to +85°C temperature range.

FUNCTIONAL BLOCK DIAGRAM OF DAC8581



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE	PACKAGE DRAWING NUMBER	SPECIFICATION TEMPERATURE RANGE	MPERATURE ORDERING		TRANSPORT MEDIA, QUANTITY	
DAC8581	TSSOP-16	PW	–40°C to +85°C	D8581I	DAC8581IPW	Tube, 90-Piece	
DACOSOT	1330P-16	30P-10 PW	-40 C to +65 C	D03011	DAC8581IPWR	Tape and Reel, 2000-Piece	

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS(1)

		UNIT		
AV _{DD} or DV _{DD} to AV _{SS}		-0.3 V to 12 V		
Digital input voltage to AV _{SS} -0.3 V to 12 V				
V _{OUT} or V _{REF} to AV _{SS} -0.3 V to 12 V				
DGND and AGND to AV _{SS}		-0.3 V to 6 V		
Operating temperature range		-40°C to +85°C		
Storage temperature range		−65°C to +150°C		
Junction temperature range (T _J max)	+150°C		
Dower dissination	Thermal impedance (θ _{JA})	118°C/W		
Power dissipation	Thermal impedance (θ _{JC})	29°C/W		

⁽¹⁾ Stresses above those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

All specifications at $T_A = T_{MIN}$ to T_{MAX} , $+AV_{DD} = +5$ V, $-AV_{DD} = -5$ V, $DV_{DD} = +5$ V (unless otherwise noted).

	o T_{MAX} , $+AV_{DD} = +5 \text{ V}$, $-AV_{DD} = -5 \text{ V}$, $DV_{DD} = +5 \text{ V}$				
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC PERFORMANCE					
Resolution		16			Bits
Linearity error	V _{REF} = 4.096 V		±0.03	±0.1	%FS
Differential linearity error			±0.25	±0.5	LSB
Gain error		1	2	3	%FS
Gain drift			±5		ppm/°C
Bipolar zero error			-5	±25	mV
Bipolar zero drift			±20		μV/°C
Total drift			±10		ppm/°C
OUTPUT CHARACTERISTICS					
Voltage output	V_{REF} up to 5.5 V, when $AV_{DD} = 6$ V, $AV_{SS} = -6$ V	-V _{REF}		V_{REF}	V
Output impedance			1		Ω
Maximum output current			±25		mA
Cattling time	$C_L < 200 \text{ pF, } R_L = 2 \text{ k}\Omega, \text{ to } 0.1\% \text{ FS, } 8\text{-V step}$		0.65		
Settling time	To 0.003% FS		1		μs
Slew rate ⁽¹⁾			35		V/µs
Code change glitch	1 LSB change around major carry		0.5		nV-S
Overshoot	Full-scale change		50		mV
Digital feedthrough (2)			0.5		nV-S
SNR	Digital sine wave input, f _{OUT} = 1 kHz, BW = 10 kHz, 2-MSPS update rate		108		dB
THD	Digital sine wave input, f _{OUT} = 20 kHz, 8-V _{PP} output, 2-MSPS update rate		-72		dB
	0.1 Hz to 10 Hz		25		μV_{PP}
Output voltage noise	At 10-kHz offset frequency		25		nV/√ Hz
	At 100-kHz offset frequency		20		nV/√Hz
Power supply rejection	VDD varies ±10%		0.75		mV/V
REFERENCE					
Reference input bandwidth	Large signal: 2-V _{PP} sine wave on 4 V DC		3		MHz
Reference input bandwidth	Small signal: 100-mV _{PP} sine wave on 4 V DC		10		MHz
Reference input voltage range		3		AV_DD	V
Reference input impedance			5		kΩ
Reference input capacitance			5		pF
DIGITAL INPUTS					
V_{IH}				$0.7 \times DV_{DD}$	V
V_{IL}		GND		0.3 x DV _{DD}	v
Input current				±1	μΑ
Input capacitance				10	pF
Power-on delay	From V _{DD} high to $\overline{\text{CS}}$ low		20		μs

⁽¹⁾ Slew rate is measured from 10% to 90% of transition when the output changes from 0 to full-scale.

⁽²⁾ Digital feedthrough is defined as the impulse injected into the analog output from the digital input. It is measured when the DAC output does not change, \overline{CS} is held high, and while SCLK and SDIN signals are toggled.



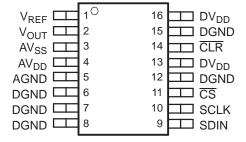
ELECTRICAL CHARACTERISTICS (continued)

All specifications at $T_A = T_{MIN}$ to T_{MAX} , +AV_{DD} = +5 V, -AV_{DD} = -5 V, DV_{DD} = +5 V (unless otherwise noted).

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY					
+AV _{DD}		4.0	5	6.0	V
-AV _{DD}		-4.0	- 5	-6.0	V
DV_DD		1.8		AV_{DD}	V
I_{DVDD}			10	20	μΑ
I _{DD}	I _{REF} and IDV _{DD} included		17	24	mA
I _{SS}			-23	-32	mA
TEMPERATURE RANGE					
Specified performance		-40		+85	°C

PIN CONFIGURATION

PW PACKAGE TSSOP-16 (TOP VIEW)



TERMINAL FUNCTIONS

		TENMINAL FORCTIONS
TE	RMINAL	
NAME	NO.	
V_{REF}	1	Reference input voltage.
VOUT	2	DAC output voltage. Output swing is ±V _{REF}
AV _{SS}	3	Negative analog supply voltage, tie to –5 V
AV_{DD}	4	Positive analog supply voltage, tie to +5 V
AGND	5	The ground reference point of all analog circuitry of the device. Tie to 0 V.
DGND	6, 7, 8, 15	Tie to DGND to ensure correct operation.
SDIN	9	Digital input, serial data. Ignored when $\overline{\text{CS}}$ is high.
SCLK	10	Digital input, serial bit clock. Ignored when $\overline{\text{CS}}$ is high.
CS	11	Digital input. Chip Select (\overline{CS}) signal. Active low. When \overline{CS} is high, SCLK and SDI are ignored. When \overline{CS} is low, data can be transferred into the device.
DGND	12	Ground reference for digital circuitry. Tie to 0 V.
DV_DD	13	Positive digital supply, 1.8 V–5.5 V compatible
CLR	14	Digital input for forcing the output to midscale. Active low. When pin $\overline{\text{CLR}}$ is low during 16 th SCLK following the falling edge of $\overline{\text{CS}}$, the falling edge of 16 th SCLK sets DAC Latch to midcode, and the DAC output to 0 V. When pin $\overline{\text{CLR}}$ is High, the falling edge of 16th SCLK updates DAC latch with the value of input shift register, and changes DAC output to corresponding level.
DV_DD	16	Tie to DV _{DD} to ensure correct operation.



TIMING REQUIREMENTS(1)

	PARAMETER	MIN	MAX	UNIT
t _{SCK}	SCLK period	20		ns
t _{WSCK}	SCLK high or low time	10		ns
t _{Lead}	Delay from falling CS to first rising SCLK	20		ns
t _{TD}	CS High between two active Periods	20		ns
t _{SU}	Data setup time (Input)	5		ns
t _H I	Data hold time (input)	5		ns
t _R	Rise time		30	ns
t _F	Fall time		30	ns
t _{WAIT}	Delay from 16th falling edge of SCLK to $\overline{\text{CS}}$ low	100		ns
t _{UPDAC}	Delay from 16th falling edge of SCLK to DAC output	1		μs
	V _{DD} High to $\overline{\text{CS}}$ Low (power-up delay)	100		μs

(1) Assured by design. Not production tested.

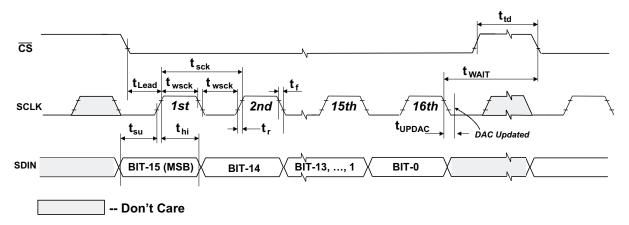


Figure 1. DAC8581 Timing Diagram



TYPICAL CHARACTERISTICS

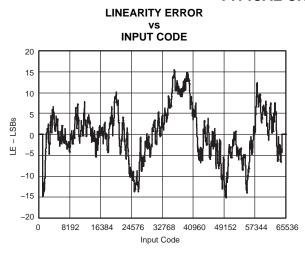


Figure 2.

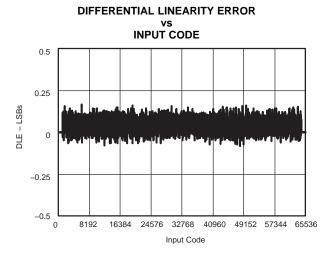


Figure 3.

INTEGRAL NONLINEARITY ERROR vs

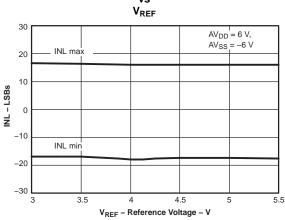


Figure 4.

INTEGRAL NONLINEARITY ERROR vs SUPPLY VOLTAGE

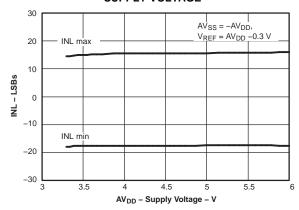


Figure 5.

OFFSET ERROR vs

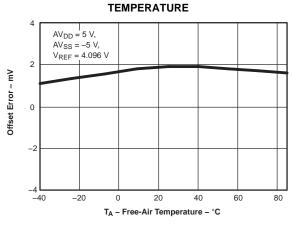


Figure 6.

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GAIN ERROR vs TEMPERATURE

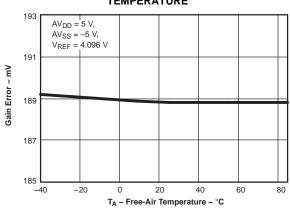


Figure 7.



TYPICAL CHARACTERISTICS (continued)

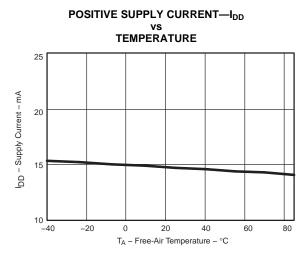


Figure 8.

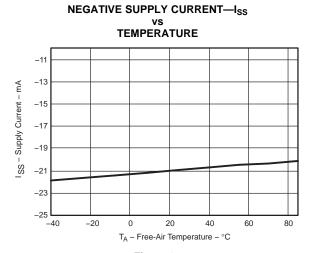


Figure 9.

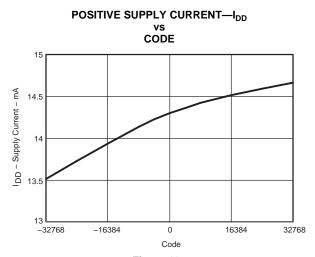


Figure 10.

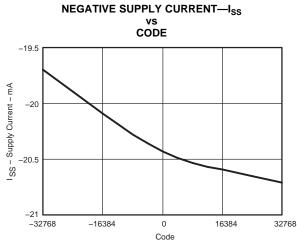


Figure 11.

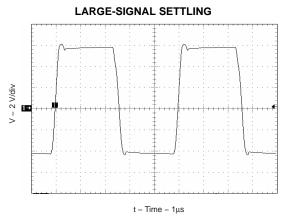


Figure 12.

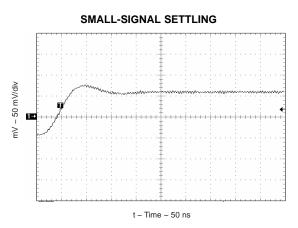
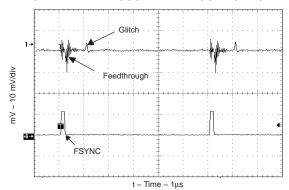


Figure 13.



TYPICAL CHARACTERISTICS (continued)

DIGITAL FEEDTHROUGH AND MIDCODE GLITCH



OUTPUT VOLTAGE NOISE

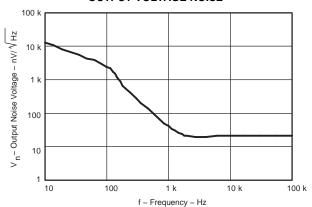
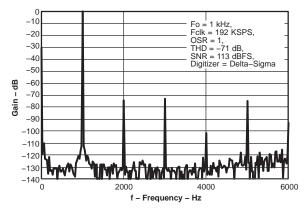


Figure 14.

Figure 15.

POWER SPECTRAL DENSITY FROM DC TO 6 kHz



SOFTWARE-TRIMMED UNIT POWER SPECTRAL DENSITY

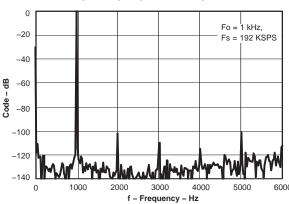


Figure 16.

Figure 17.

SOFTWARE-TRIMMED UNIT LINEARITY ERROR INPUT CODE

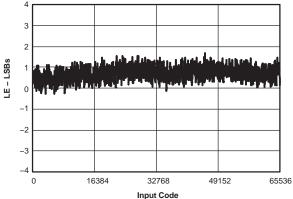


Figure 18.

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THEORY OF OPERATION

The DAC8581 uses a proprietary, monotonic, high-speed resistor string architecture. The 16-bit input data are coded in twos complement, MSB-first format and transmitted using a 3-wire serial interface. The serial interface sends the input data to the DAC latch. The digital data are then decoded to select a tap voltage of the resistor string. The resistor string output is sent to a high-performance output amplifier. The output buffer has rail-to-rail (± 5 V) swing capability on a 600- Ω , 200-pF load. The resistor string DAC architecture provides exceptional differential linearity and temperature stability whereas the output buffer provides fast-settling, low-glitch, and exceptionally low idle-channel noise. The DAC8581 settles within 1 μ s for large input signals. Exceptionally low glitch (0.5 nV-s) is attainable for small-signal, code-to-code output changes. The resistor string architecture also provides code-independent power consumption and code-independent settling time. The DAC8581 resistor string needs an external reference voltage to set the output voltage range of the DAC. To aid fast settling, V_{REF} input is internally buffered.

Supply Pins

The DAC8581 uses ± 5 -V analog power supplies (AV_{DD}, AV_{SS}) and a 1.8-V to 5.5-V digital supply (DV_{DD}). Analog and digital ground pins (AGND and DGND) are also provided. For low-noise operation, analog and digital power and ground pins should be separated. Sufficient bypass capacitors, at least 1 μ F, should be placed between AV_{DD} and AV_{SS}, AV_{SS} and DGND, and DV_{DD} and DGND pins. Series inductors are *not* recommended on the supply paths. The digital input pins should not exceed the ground potential during power up. During power up, AGND and DGND are first applied with all digital inputs and the reference input kept at 0 V. Then, AV_{DD}, DV_{DD}, AV_{SS}, and V_{REF} should be applied together. Care should be taken to avoid applying V_{REF} before AV_{DD} and AV_{SS}. All digital pins must be kept at ground potential before power up.

Reference Input Voltage

The reference input pin V_{REF} is typically tied to a +3.3-V, +4.096-V, or +5.0-V external reference. A bypass capacitor (0.1 μ F or less) is recommended, depending on the load-driving capability of the voltage reference. To reduce crosstalk and improve settling time, the V_{REF} pin is internally buffered by a high-performance amplifier. The V_{REF} pin has constant 5-k Ω impedance to AGND. The output range of the DAC8581 is equal to $\pm V_{REF}$ voltage. The V_{REF} pin should be powered at the same time, or after the supply pins. REF3133 and REF3140 are recommended to set the DAC8581 output range to ± 3.3 V and ± 4.096 V, respectively.

Output Voltage

The input data format is in twos-complement format as shown in Table 1. The DAC8581 uses a high-performance, rail-to-rail output buffer capable of driving a 600- Ω , 200-pF load with fast 0.65- μ s settling. The buffer has exceptional noise performance ($20 \text{ nV}/\sqrt{\text{Hz}}$) and fast slew rate ($35 \text{ V}/\mu$ s). The small-signal settling time is under 300 ns, allowing update rates up to 3 MSPS. Loads of 50Ω or 75Ω could be driven as long as output current does not exceed $\pm 25 \text{ mA}$ continuously. Long cables, up to 1 nF in capacitance, can be driven without the use of external buffers. To aid stability under large capacitive loads (>1 nF), a small series resistor can be used at the output.

DIGITAL CODE DAC OUTPUT BINARY HEX 7FFF 01111111111111111 $+V_{REF}$ $+V_{REF}/2$ 0100000000000000 4000 0 0000 0000000000000000 10111111111111111 **BFFF** $-V_{REF}/2$ 1000000000000000 -V_{REF} 8000

Table 1. Data Format



Glitch area is low at 0.5 nV-s, with peak glitch amplitude under 10 mV, and the glitch duration under 100 ns. Low glitch is obtained for code-to-code (small signal) changes across the entire transfer function of the device. For large signals, settling characteristics of the reference and output amplifiers are observed in terms of overshoot and undershoot.

Combined with ±5-V output range, and extremely good noise performance, the outstanding differential linearity performance of this device becomes significant. That is, each DAC step can be clearly observed at the DAC output, without being corrupted by wideband noise.

SERIAL INTERFACE

The DAC8581 serial interface consists of the serial data input pin SDIN, bit clock pin SCLK, and chip-select pin, $\overline{\text{CS}}$. The serial interface is designed to support the industry standard SPI interface up to 50 MHz. The serial inputs are 1.8-V to 5.5-V logic compatible.

 $\overline{\text{CS}}$ operates as an active-low, chip-select signal. The falling edge of $\overline{\text{CS}}$ initiates the data transfer. Each rising edge of SCLK following the falling edge of $\overline{\text{CS}}$ shifts the SDIN data into a 16-bit shift register, MSB-first. At the 16th rising edge of SCLK, the shift register becomes full and the DAC data updates on the falling edge that follows the 16th rising edge. After the data update, further clocking gets ignored. The sequence restarts at the next falling edge of $\overline{\text{CS}}$. If the $\overline{\text{CS}}$ is brought high before the DAC data are updated, the data are ignored. See the timing diagram (Figure 1) for details.

Pin CLR

Pin $\overline{\text{CLR}}$ is implemented to set the DAC output to 0 V. When the $\overline{\text{CS}}$ pin is low during the 16th SCLK cycle following the falling edge of $\overline{\text{CS}}$, the falling edge of the 16th SCLK sets the DAC latch to midcode, and the DAC output to 0 V. If the $\overline{\text{CLR}}$ pin is high during the 16th clock, the falling edge of the 16th clock updates the DAC latch with the input data. Therefore, if the $\overline{\text{CLR}}$ pin is brought back to High from Low during serial communication, the DAC output stays at 0 V until the falling edge of the next 16th clock is received. The $\overline{\text{CLR}}$ pin is active low. $\overline{\text{CLR}}$ low does not affect the serial data transfer. The serial data input doe not get interrupted or lost while the output is set at midscale.

SCLK

This digital input pin is the serial bit-clock. Data are clocked into the device at the rising edge of SCLK.

CS

This digital input pin is the chip-select signal. When \overline{CS} is low, the serial port is enabled and data can be transferred into the device. When \overline{CS} is high, all SCLK and SDIN signals are ignored.

SDIN

This digital input is the serial data input. Serial data are shifted on the rising edge of the SCLK when \overline{CS} is low.



APPLICATION INFORMATION

IMPROVING DAC8581 LINEARITY USING EXTERNAL CALIBRATION

At output frequencies up to 50 kHz, DAC8581 linearity error and total harmonic distortion are dominated by resistor mismatches in the string. These resistor mismatches are fairly insensitive to temperature and aging effects and also to reference voltage changes. Therefore, it is possible to use a piece-wise linear (PWL) approximation to cancel linearity errors, and the calibration remains effective for different supply and V_{REF} voltages, etc. The cancellation of linearity errors also improves the total harmonic distortion (THD) performance. It is possible to improve the integral linearity errors from ± 25 LSB to ± 1 LSB and the THD from \pm

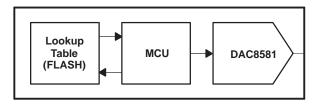


Figure 19. A Simple Printed-Circuit Board Scheme for Calibrated Use of DAC8581

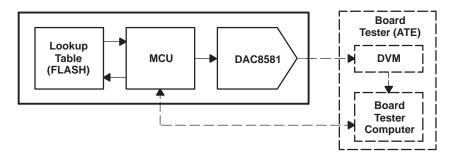


Figure 20. Production Test Setup for a DAC8581 Board With Calibration

The PWL calibration scheme uses a DAC8581 and a microcontroller unit (MCU) with flash memory, on a printed-circuit board as seen in Figure 19. Calibration is done during board test, and the calibration coefficients are stored permanently in flash memory as seen in Figure 20. An automated board tester is assumed to have a precision digital voltmeter (DVM) and a tester computer. The test flow for a 1024-segment, piece-wise linear calibration is as follows:

- 1. Use the tester computer to load software into the MCU to ramp the DAC8581 and:
 - Take a reading at each step after a short wait time
 - Store 65,536 readings in the tester computer volatile memory
- 2. Use the tester computer to:
 - Search the 65,536-point capture data and find the actual DAC8581 codes which would generate ideal DAC outputs for DAC input codes 0, 64, 128, 192,
 - Store these actual codes in the onboard microcontroller's flash memory in a 1025-point array called COEFF[].
- 3. Use the tester computer to program the MCU such that, when the end-user provides new 16-bit input data D0 to the MCU:
 - The 10 MSBs of D0 directly index the array COEFF[].
 - The content of indexed memory of COEFF[] and the content of the next higher memory location are placed in variables I1 and I2.
 - The six LSBs of the user data D0 with two variables I1 and I2 are used for computing Equation 1 (see Figure 21).
 - Instead of D0, I0 is loaded to DAC8581



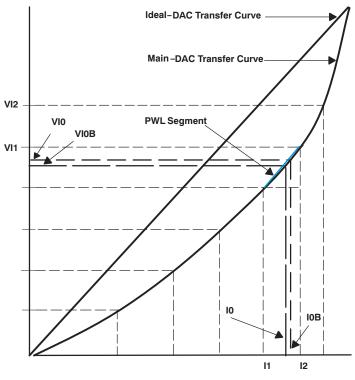


Figure 21. The Geometry Behind the PWL Calibration

$$I0 = \frac{I1 + (I2 - I1)(D0 - VI1)}{VI2 - VI1}$$
(1)

Where both x-axis and y-axis are normalized from 0 to 65535, and:

- VIO: Desired ideal DAC voltage corresponding to input code D0.
- VIOB: DAC8581 output voltage, which approximates VIO after PWL calibration. This is the actual DAC8581 output for input code D0 after PWL calibration.
 - I0: DAC8581 code generating VI0B, an approximation to the desired voltage VI0. This is actual code loaded into DAC latch for input code D0, after PWL calibration.
 - IOB: DAC8581 code, which generates output VIO. This code is approximated by the N-segment PWL calibration.
 - I1: Contents of memory COEFF[], addressed by the 10 MSBs of user input code D0.
 - 12: Contents of the next memory location in COEFF[].
 - VI1: DAC8581 output voltage corresponding to code I1. Notice that (D0–VI1) is nothing but the six LSBs of the input code D0, given that the y-axis is normalized from 0 to 65,536.
 - VI2: DAC8581 output voltage corresponding to code I2. Notice that (VI2–VI1) is always equal to number 64, given that the y-axis is normalized from 0 to 65,536. Division becomes a 6-bit arithmetic right shift.

Other similar PWL calibration implementations exist. This particular algorithm does not need digital division, and it does not accumulate measurement errors at each segment.



REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision A (August, 2005) to Revision B	Page
•	Updated document format to current stylistic standards	1
•	Deleted lead temperature specifications from Absolute Maximum Ratings table	2
•	Deleted footnote 1 from Electrical Characteristics table	3
•	Revised test conditions for voltage output specification	3



PACKAGE OPTION ADDENDUM

www.ti.com 10-Sep-2009

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
DAC8581IPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC8581IPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC8581IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC8581IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

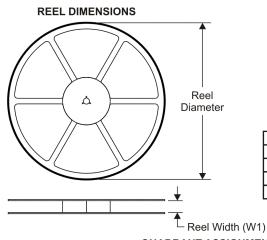
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

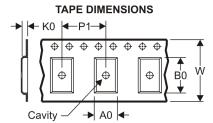
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TAPE AND REEL INFORMATION





Α	0	Dimension designed to accommodate the component width
В	0	Dimension designed to accommodate the component length
		Dimension designed to accommodate the component thickness
٧	٧	Overall width of the carrier tape
ГР	1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC8581IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



PACKAGE MATERIALS INFORMATION

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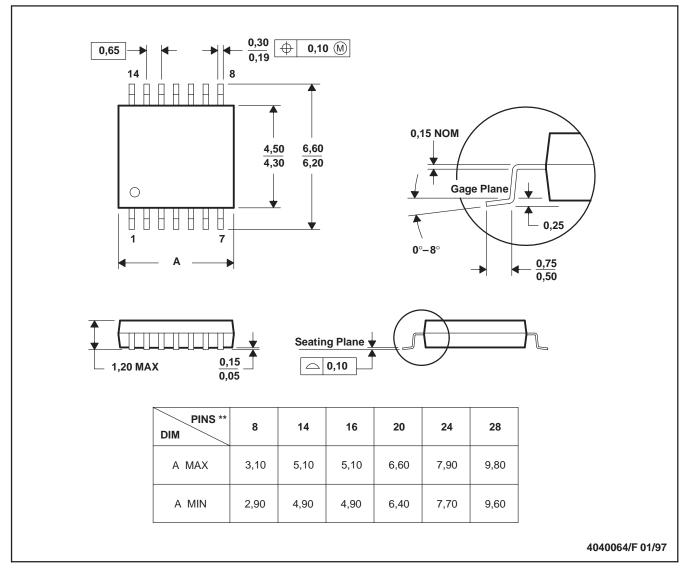
*All dimensions are nominal

ĺ	Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
	DAC8581IPWR	TSSOP	PW	16	2000	346.0	346.0	29.0	

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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